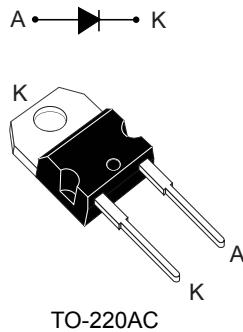


## 120 V power Schottky rectifier



### Features

- High junction temperature capability
- Avalanche rated
- Low leakage current
- Good trade-off between leakage current and forward voltage drop
- ECOPACK®2 compliant

### Applications

- Switching diode
- SMPS
- DC/DC converter
- LED lighting
- Notebook adapter

### Description

This single Schottky rectifier is suited for high frequency switch mode power supply. Packaged in TO-220AC, the **STPS20120D** is optimized for use in notebook & LCD adaptors, desktop SMPS, providing in these applications a margin between the remaining voltages applied on the diode and the voltage capability of the diode.

Product status link	
<a href="#">STPS20120D</a>	
Product summary	
Symbol	Value
$I_{F(AV)}$	20 A
$V_{RRM}$	120 V
$T_j$ (max.)	175 °C
$V_F$ (typ.)	0.72 V

## 1 Characteristics

**Table 1. Absolute ratings (limiting values at 25 °C unless otherwise specified)**

Symbol	Parameter		Value	Unit	
$V_{RRM}$	Repetitive peak reverse voltage		120	V	
$I_{F(RMS)}$	Forward rms current		30	A	
$I_{F(AV)}$	Average forward current, $\delta = 0.5$ square wave		$T_c = 130$ °C	20	A
$I_{FSM}$	Surge non repetitive forward current		$t_p = 10$ ms sinusoidal	200	A
$P_{ARM}$	Repetitive peak avalanche power		$t_p = 10$ µs, $T_j = 125$ °C	619	W
$T_{stg}$	Storage temperature range			-65 to +175	°C
$T_j$	Maximum operating junction temperature <sup>(1)</sup>			175	°C

1.  $(dP_{tot}/dT_j) < (1/R_{th(j-a)})$  condition to avoid thermal runaway for a diode on its own heatsink.

**Table 2. Thermal resistance parameters**

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	Junction to case	2.2	°C/W

**Table 3. Static electrical characteristics**

Symbol	Parameter	Test conditions		Min.	Typ.	Max.	Unit
$I_R^{(1)}$	Reverse leakage current	$T_j = 25$ °C	$V_R = V_{RRM}$	-		20	µA
		$T_j = 125$ °C		-	3	10	mA
$V_F^{(2)}$	Forward voltage drop	$T_j = 25$ °C	$I_F = 5$ A	-		0.70	V
		$T_j = 125$ °C		-	0.54	0.58	
		$T_j = 25$ °C	$I_F = 10$ A	-		0.80	
		$T_j = 125$ °C		-	0.62	0.66	
		$T_j = 25$ °C	$I_F = 20$ A	-		0.93	
		$T_j = 125$ °C		-	0.72	0.76	

1. Pulse test:  $t_p = 5$  ms,  $\delta < 2\%$

2. Pulse test:  $t_p = 380$  µs,  $\delta < 2\%$

To evaluate the conduction losses, use the following equation:

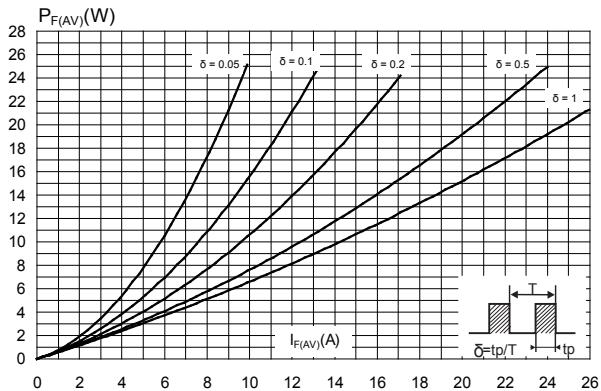
$$P = 0.56 \times I_{F(AV)} + 0.010 \times I_{F(RMS)}^2$$

For more information, please refer to the following application notes related to the power losses :

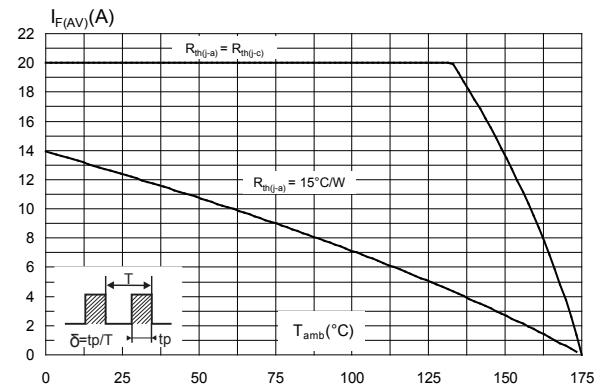
- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses on a power diode

## 1.1 Characteristics (curves)

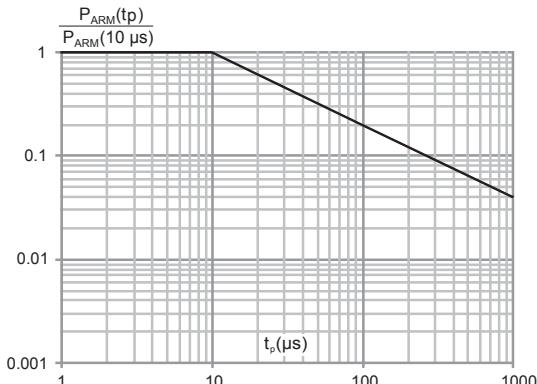
**Figure 1. Average forward power dissipation versus average forward current**



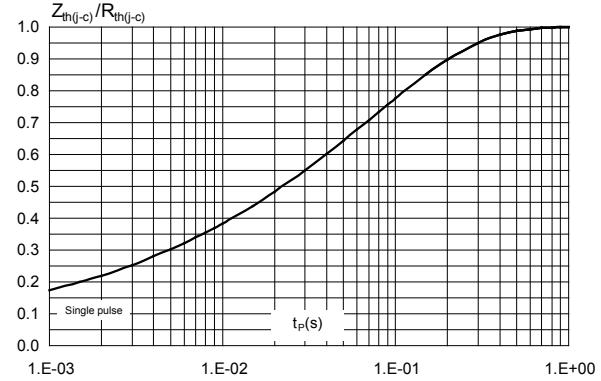
**Figure 2. Average forward current versus ambient temperature ( $\delta = 0.5$ )**



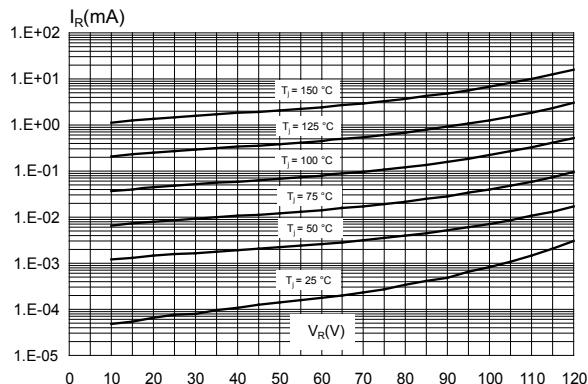
**Figure 3. Normalized avalanche power derating versus pulse duration ( $T_j = 125$  °C)**



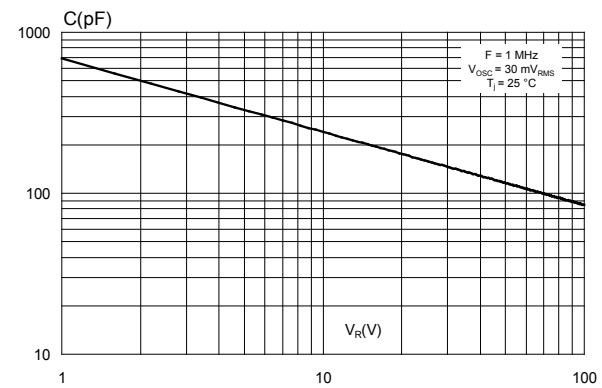
**Figure 4. Relative variation of thermal impedance junction to case versus pulse duration**



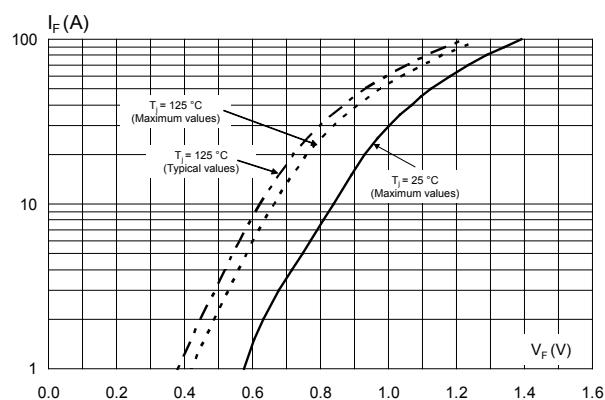
**Figure 5. Reverse leakage current versus reverse voltage applied (typical values)**



**Figure 6. Junction capacitance versus reverse voltage applied (typical values)**



**Figure 7. Forward voltage drop versus forward current**



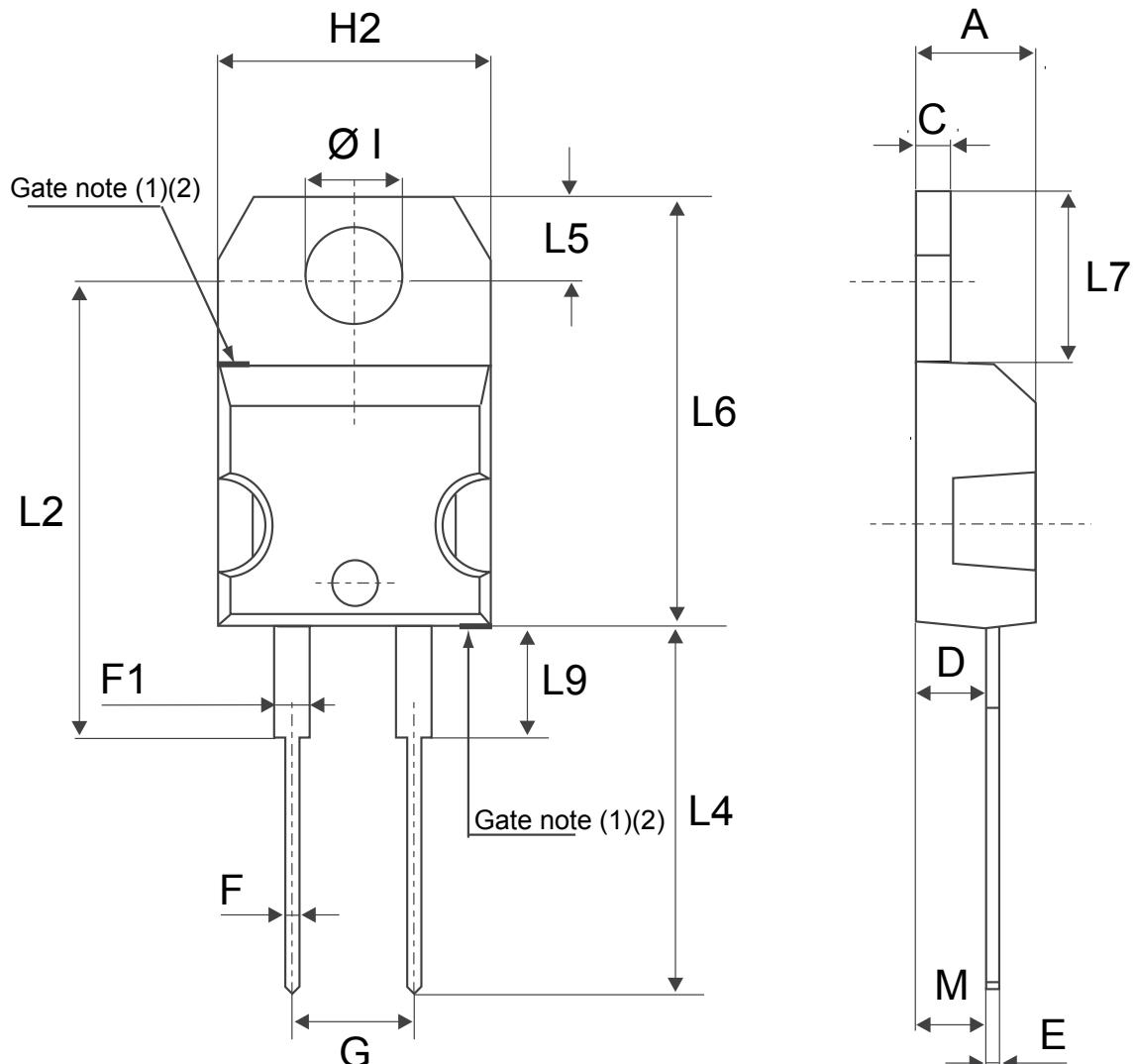
## 2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK® is an ST trademark.

### 2.1 TO-220AC package information

- Epoxy meets UL 94,VO
- Cooling method: by conduction (C)
- Recommended torque value: 0.55 N·m
- Maximum torque value: 0.70 N·m

Figure 8. TO-220AC package outline



(1) :Max resin gate protusion 0.5 mm

(2) :Resin gate position is accepted in each of the two positions shown on the drawings or their symmetrical

**Table 4. TO-220AC package mechanical data**

Ref.	Dimensions			
	Millimeters		Inches (for reference only)	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
C	1.23	1.32	0.048	0.051
D	2.40	2.72	0.094	0.107
E	0.49	0.70	0.019	0.027
F	0.61	0.88	0.024	0.034
F1	1.14	1.70	0.044	0.066
G	4.95	5.15	0.194	0.202
H2	10.00	10.40	0.393	0.409
L2	16.40 typ.		0.645 typ.	
L4	13.00	14.00	0.511	0.551
L5	2.65	2.95	0.104	0.116
L6	15.25	15.75	0.600	0.620
L7	6.20	6.60	0.244	0.259
L9	3.50	3.93	0.137	0.154
M	2.60 typ.		0.102 typ.	
Diam	3.75	3.85	0.147	0.151

### 3 Ordering information

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**Table 5. Ordering information**

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPS20120D	STPS20120D	TO-220AC	1.86 g	50	Tube

## Revision history

**Table 6. Document revision history**

Date	Version	Changes
18-Feb-2005	1	First issue.
02-Jul-2018	2	Removed figure 4 and figure 5. Updated Figure 3. Normalized avalanche power derating versus pulse duration ( $T_j = 125^\circ\text{C}$ ) and Table 1. Absolute ratings (limiting values at $25^\circ\text{C}$ unless otherwise specified). Minor text changes to improve readability.

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